

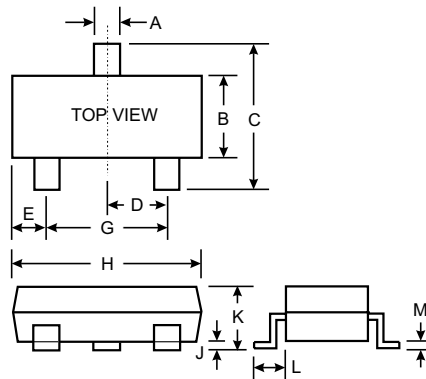
Features

- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection

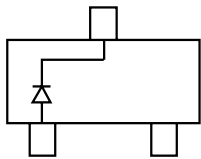
Mechanical Data

- Case: SOT-23, Molded Plastic
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagrams
- Approx. Weight: 0.008 grams

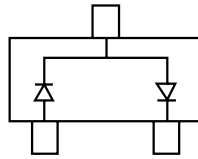
**DISCONTINUED -
USE BAS70 SERIES**



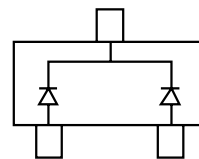
SOT-23		
Dim	Min	Max
A	0.37	0.51
B	1.19	1.40
C	2.10	2.50
D	0.89	1.05
E	0.45	0.61
G	1.78	2.05
H	2.65	3.05
J	0.013	0.15
K	0.89	1.10
L	0.45	0.61
M	0.076	0.178
All Dimensions in mm		



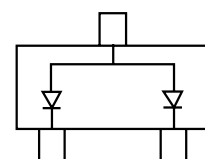
BAS70H Marking: K73



BAS70H-04 Marking: K74



BAS70H-05 Marking: K75



BAS70H-06 Marking: K76

Maximum Ratings and Electrical Characteristics, Single Diode @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	BAS70	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	70	V
Working Peak Reverse Voltage	V _{RWM}		
DC Blocking Voltage	V _R		
RMS Reverse Voltage	V _{R(RMS)}	49	V
Forward Continuous Current (Note 1)	I _F	200	mA
Non-Repetitive Peak Forward Surge Current @ t _p < 1.0s	I _{FSM}	600	mA
Power Dissipation (Note 1)	P _d	200	mW
Thermal Resistance Junction to Ambient Air (Note 1)	R _{θJA}	625	K/W
Operating and Storage Temperature Range	T _j	-55 to +125	°C
Storage Temperature Range	T _{STG}	-65 to +150	°C

Electrical Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 2)	V _{(BR)R}	70	—	V	I _R = 10μA
Forward Voltage	V _F	—	410 1000	mV	t _p < 300μs, I _F = 1.0mA t _p < 300μs, I _F = 15mA
Peak Reverse Current	I _{RM}	—	100	nA	t _p < 300μs, V _R = 50V
Junction Capacitance	C _j	—	2.0	pF	V _R = 0V, f = 1.0MHz
Reverse Recovery Time	t _{rr}	—	5.0	ns	I _F = I _R = 10mA to I _R = 1.0mA, R _L = 100Ω

Notes: 1. Valid Provided that terminals are kept at ambient temperature.
2. Test period <3000μs.